Amendments to the Claims:

The following listing of claims will replace all prior versions, and listings, of claims in the application:

- 1-3. (Canceled)
- 4. (Currently Amended) The anti-reflective coating forming composition-process for manufacturing a semiconductor device according to elaim 1claim 11, wherein the anti-reflective coating forming composition further containing comprises a light absorbing compound and/or a light absorbing resin.
- 5. (Currently Amended) The anti-reflective coating forming composition-process for manufacturing a semiconductor device according to claim 4, wherein the light absorbing compound is at least one compound selected from naphthalene compounds and anthracene compounds.
- 6. (Currently Amended) The anti-reflective coating forming composition-process for manufacturing a semiconductor device according to claim 4, wherein the light absorbing compound is at least one compound selected from triazine compounds and triazine trione compounds.
- 7. (Currently Amended) The anti-reflective coating forming composition process for manufacturing a semiconductor device according to claim 4, wherein the light absorbing resin is a resin having in the structure at least one aromatic ring structure selected from benzene ring, naphthalene ring and anthracene ring.
- 8. (Currently Amended) The anti-reflective coating forming composition process for manufacturing a semiconductor device according to elaim 1claim 11, wherein the anti-reflective coating forming composition further containing comprises a resin having at lease one crosslink-forming substituent selected from hydroxy group, carboxy group, amino group and thiol group.

9-10. (Canceled)

11. (Currently Amended) A process for manufacturing a semiconductor device, characterized by comprising the steps of:

coating <u>an anti-reflective</u> coating forming composition according to claim 1 on a substrate and baking it to form an anti-reflective coating;

wherein the anti-reflective coating forming composition comprises a compound of formula (1), a condensation product thereof or a resin produced from the compound

$$R_2OH_2C$$
 N
 CH_2OR_1
Formula (1)

wherein R_1 and R_2 are independently of each other hydrogen atom or an alkyl group, R_3 and R_4 are independently of each other hydrogen atom, methyl group, ethyl group, hydroxymethyl group or an alkoxymethyl group, and an acid and/or acid generator, and the compound, the condensation product thereof or the resin produced from the compound is contained in an amount of 50 mass% or more in a solid content of the anti-reflective coating forming composition;

forming a photoresist on top of the anti-reflective coating;

exposing the substrate covered with the anti-reflective coating and the photoresist with a light;

_____developing it;

transferring an image on the substrate by etching to form an integrated circuit device.